

Page 1 of 1 FORM PTO-1449 LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	Atty. Docket No.: H0004823 (1139.1140101)	Serial No.: 10/606,104
	Applicant: Txu-Yu Wang et al.	
	Filing Date: June 25, 2003	Group Art: 2828 unknown

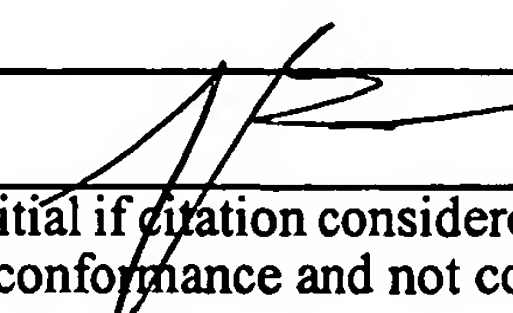
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pn	5,625,202	04/1997	Chai			
	5,661,075	08/1997	Grodzinski et al.			
	5,747,366	05/1998	Brillouet et al.			
	5,835,521	11/1998	Ramdani et al.			
	5,864,575	01/1999	Ohiso et al.			
	5,978,398	11/1999	Ramdani et al.			
	6,546,031	04/2003	Jewell et al.			
	6,553,051	04/2003	Tan et al.			

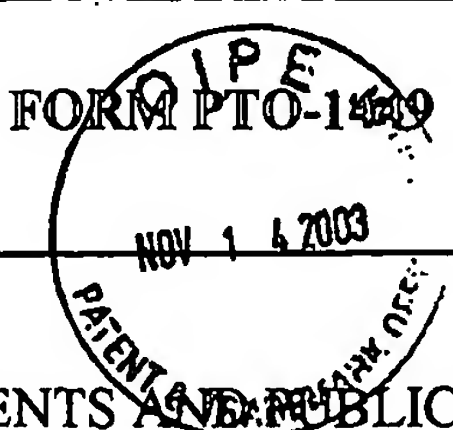
FOREIGN PATENT DOCUMENTS

Examiner Initial	Document No.	Date	Country	Translation Yes No

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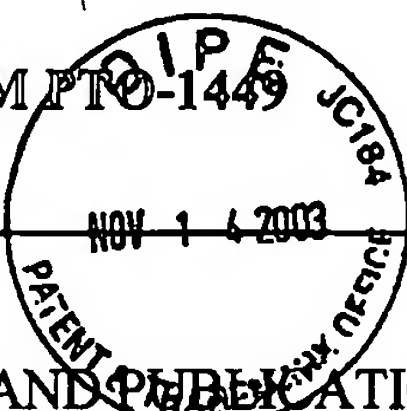
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Page 1 of 13		Atty. Docket No.: H0004823 (1139.1140101)	Serial No.: 10/606,104
		Applicant: Tzu-Yu Wang et al.	
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT		Filing Date: June 25, 2003	Group Art: 2828 unknown

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	4,660,207	04/21/1987	Svilans			
	4,675,058	06/23/1987	Plaster			
	4,784,722	11/15/1988	Liau et al.			
	4,885,592	12/05/1989	Kofol et al.			
	4,901,327	02/13/1990	Bradley			
	4,943,970	07/24/1990	Bradley			
	4,956,844	09/11/1990	Goodhue et al.			
	5,031,187	07/09/1991	Orenstein et al.			
	5,052,016	09/24/1991	Mahbobzadeh			
	5,056,098	10/08/1991	Anthony et al.			
	5,062,115	10/29/1991	Thornton			
	5,068,869	11/26/1991	Wang et al.			
	5,079,774	01/07/1992	Mendez et al.			
	5,115,442	05/19/1992	Lee et al.			
	5,117,469	05/26/1992	Cheung et al.			
	5,140,605	08/18/1992	Paoli et al.			
	5,157,537	10/20/1992	Rosenblatt et al.			
	5,158,908	10/27/1992	Blonder et al.			
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Page 2 of 13	FORM PTO-1449 	Atty. Docket No.: H0004823 (1139.1140101)	Serial No.: 10/606,104
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT		Applicant: Tzu-Yu Wang et al.	
		Filing Date:	Group Art: 2828
		June 25, 2003	unknown

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PN	5,216,263	06/01/1993	Paoli			
	5,216,680	06/01/1993	Magnusson et al.			
	5,237,581	08/17/1993	Asada et al.			
	5,245,622	09/14/1993	Jewell et al.			
	5,258,990	11/02/1993	Olbright et al.			
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	5,285,466	02/08/1994	Tabatabaie			
	5,293,392	03/08/1994	Shieh et al.			
	5,317,170	05/31/1994	Paoli			
	5,317,587	05/31/1994	Ackley et al.			
	5,325,386	06/28/1994	Jewell et al.			
	5,331,654	07/19/1994	Jewell et al.			
	5,337,074	08/09/1994	Thornton			
	5,337,183	08/09/1994	Rosenblatt et al.			
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Page 3 of 13	FORM PTO 1449E NOV 1 6 2003 PATENT OFFICE	Atty. Docket No.: H0004823 (1139.1140101)	Serial No.: 10/606,104
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT		Applicant: Tzu-Yu Wang et al.	
		Filing Date:	Group Art: 2828
		June 25, 2003	unknown

Examiner Initial	Document No.	Date	Name	Class	Sub Class	Filing Date If Appropriate
PW	5,396,508	03/17/1995	Bour et al.			
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	5,412,678	05/02/1995	Treat et al.			
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	5,557,626	09/17/1996	Grodinski et al.			
	5,561,683	10/01/1996	Kwon			
	5,567,980	10/22/1996	Holonyak, Jr. et al.			
	5,568,498	10/22/1996	Nilsson			
	5,568,499	10/22/1996	Lear			
	5,574,738	11/12/1996	Morgan			
	5,581,571	12/1996	Holonyak, Jr. et al.			
	5,586,131	12/17/1996	Ono et al.			
	5,590,145	12/31/1996	Nitta			
	5,598,300	01/28/1997	Magnusson et al.			

Page 4 of 13	FORM PTO-100	Atty. Docket No.: H0004823 (1139.1140101)	Serial No.: 10/606,104
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT		Applicant: Tzu-Yu Wang et al.	
		Filing Date: June 25, 2003	Group Art: 2828 unknown

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PN	5,606,572	02/25/1997	Swirhun et al.			
	5,625,729	04/29/1997	Brown			
	5,642,376	06/24/1997	Olbright et al.			
	5,645,462	07/08/1997	Banno et al.			
	5,646,978	07/08/1997	Kem et al.			
	5,648,978	07/15/1997	Sakata			
	5,679,963	10/21/1997	Klem et al.			
	5,692,083	11/25/1997	Bennett			
	5,696,023	12/09/1997	Holonyak, Jr., et al.			
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	5,727,013	03/10/1988	Botez et al.			
	5,727,014	03/10/1988	Wang et al.			
	5,774,487	06/30/1998	Morgan			
	5,778,018	07/07/1998	Yoshikawa et al.			
	5,781,575	07/14/1998	Nilsson			
	5,784,399	07/21/1998	Sun			
	4,790,733	08/04/1998	Smith et al.			
	5,805,624	09/08/1998	Yang et al.			
	5,818,066	10/06/1998	Duboz			
	5,828,684	10/27/1998	Van de Walle			
	5,838,705	11/17/1998	Shieh et al.			
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Page 5 of 13	FORM PTO-1449 NOV 1 4 2003 PATENT & TRADEMARK OFFICE	Atty. Docket No.: H0004823 (1139.1140101)	Serial No.: 10/606,104
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT		Applicant: Tzu-Yu Wang et al.	
		Filing Date: June 25, 2003	Group Art: 2828 unknown

Examiner Initial	Document No.	Date	Name	Class	Sub Class	Filing Date If Appropriate
pn	5,892,784	04/06/1999	Tan et al.			
	5,892,787	04/06/1999	Tan et al.			
	5,896,408	04/20/1999	Corzine et al.			
	5,901,166	05/04/1999	Nitta et al.			
	5,903,588	05/1999	Guenter et al.			
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	5,903,590	05/11/1999	Hadley et al.			
	5,908,408	06/1999	McGary et al.			
	5,936,266	08/10/1999	Holonyak, Jr. et al.			
	5,940,422	08/17/1999	Johnson			
	5,953,362	09/14/1999	Pamulapati et al.			
	5,978,401	11/02/1999	Morgan			
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	5,995,531	11/30/1999	Gaw et al.			
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V	6,133,590	10/17/2000	Ashley et al.			

Page 6 of 13	FORM PTO-1449	Atty. Docket No.: H0004823 (1139.1140101)	Serial No.: 10/606,104
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT		Applicant: Tzu-Yu Wang et al.	
		Filing Date: June 25, 2003	Group Art: 2828 unknown

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PN	6,144,682	11/07/2000	Sun			
	6,154,480	11/28/2000	Magnusson et al.			
	6,185,241	02/06/2001	Sun			
	6,191,890	02/20/2001	Baets et al			
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	6,212,312	04/03/2001	Grann et al			
	6,238,944 B1	05/29/2001	Floyd			
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	6,369,403	04/09/2002	Holonyak, Jr.			
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	6,392,257	05/21/2002	Ramdani et al.			
	6,410,941	06/25/2002	Taylor et al.			
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	6,427,066	07/30/2002	Grube			
	6,455,879	09/24/2002	Ashley et al.			
	6,459,709	10/01/2002	Lo et al.			
	6,459,713	10/01/2002	Jewell			
	6,462,360	10/08/2002	Higgins, Jr. et al.			
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	6,487,230	11/26/2002	Boucart et al.			

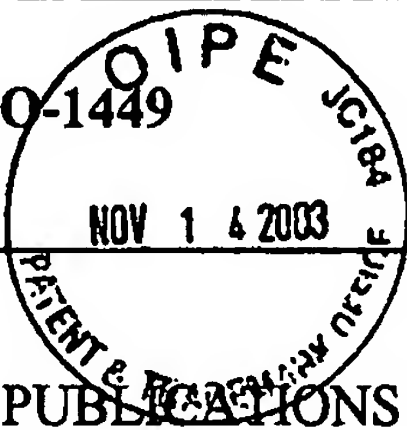
Page 7 of 13	FORM PTO-1049P E	Atty. Docket No.: H0004823 (1139.1140101)	Serial No.: 10/606,104
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT		Applicant: Tzu-Yu Wang et al.	
		Filing Date: June 25, 2003	Group Art: 2828 unknown

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PN	6,487,231	11/26/2002	Boucart et al.			
	6,490,311	12/03/2002	Boucart et al.			
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	6,515,308	02/04/2003	Kneissl et al.			
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PN	JP 60123084 /	01/07/1985	JP	Abstract
	EP 0288184 A2 /	10/26/1988	EP	
	JP 02054981 /	02/23/1990	JP	Abstract
	JP 5299779 /	11/12/1993	JP	Abstract
	DE 4240706 A1 /	06/09/1994	DE	Abstract
	EP 0776076 A1 /	05/28/1997	EP	Abstract
	WO 98/57402 /	12/17/1998	PCT	

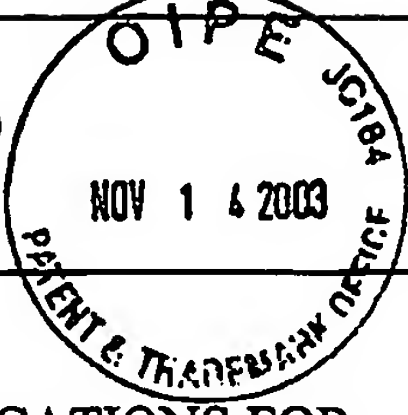
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

Page 8 of 13	FORM PTO-1449 	Atty. Docket No.: H0004823 (1139.1140101)	Serial No.: 10/606,104
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT		Applicant: Tzu-Yu Wang et al.	
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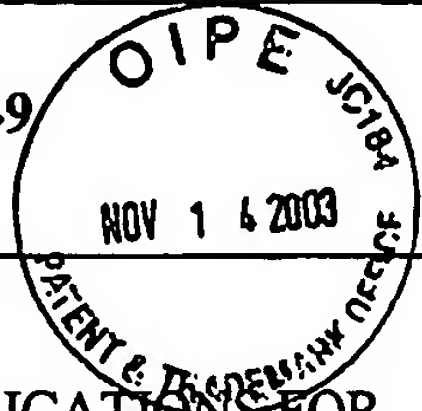
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Page 9 of 13 FORM PTO-1449 <div data-bbox="709 85 1015 399" style="text-align: center;">  </div>	Atty. Docket No.: H0004823 (1139.1140101)	Serial No.: 10/606,104
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Page 10 of 13	FORM PTO-1449		Atty. Docket No.: H0004823 (1139.1140101)	Serial No.: 10/606,104
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT			Applicant: Tzu-Yu Wang et al.	
			Filing Date: June 25, 2003	Group Art: 2828 unknown

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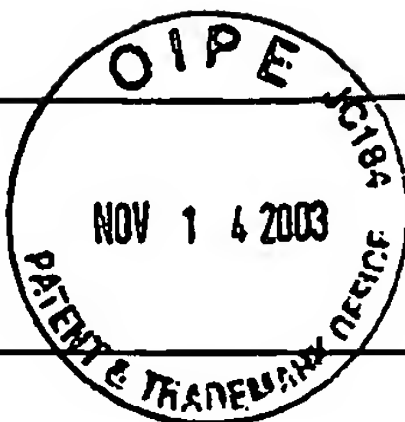
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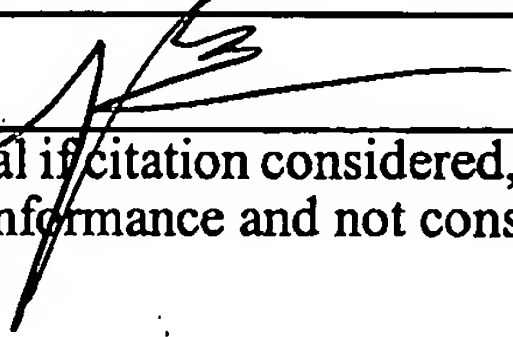
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EXAMINER: 	DATE CONSIDERED: 12/11/04
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